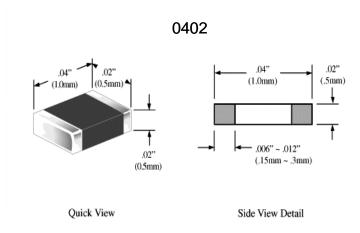


Transient Voltage Suppressors for ESD Protection

>> Features

- 0402inch/ 1005mm foot print
- Ideal ESD protection for high frequency, low voltage applications.
- Exceeds testing requirements outlined in IEC 61000-4-2
- Ultra low capacitance (1.5pF typ.)
- Very low leakage current
- Fast response time
- Bi-directional
- MSL 3



Package Dimension

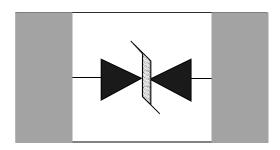
»Applications

- High Speed Data Ports (USB 2.0, IEEE 1394)
- Computers & Peripherals (Cell phone, PDA, HDTV, DVD players)

>> Mechanical Data

- Surface mount
- RoHS Compliant

>>Schematic & PIN Configuration





»Absolute Maximum Rating

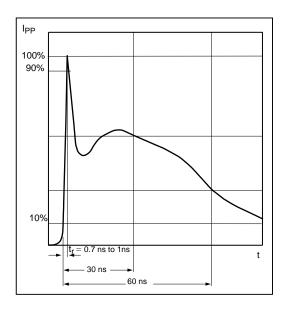
Rating	Symbol	Conditions	Value	Units	
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V _{ESD}		8 15	kV	
Lead Soldering Temperature	$T_{\rm L}$		260(10seconds)	$^{\circ}$	
Operating Temperature	To		-55 to + 125	$^{\circ}$ C	
Storage Temperature	T_{stg}		-40 to + 125	°C	

»Electrical Characteristics

Parameter	Symbol	Conditions	Min	Typical	Max	Units
Continuous Operating Voltage	V_{DC}				24	V
Trigger Voltage	V_{T}	IEC61000-4-2 8KV contact discharge		140		V
Leakage Current	I_{L}	VDC=5V,T=25 °C			500	nA
Clamping Voltage	$V_{\rm C}$	IEC61000-4-2 8KV contact discharge		65	100	V
Capacitance	C_{P}	Measured at 10MHz		1.5		pF
ESD Pulse Withstand	Pulses	IEC61000-4-2 8KV contact discharge	1000			



>>ESD Wave From



»Electrical Characteristics

SEVERITY LEVEL	AIR DIRCHARGE	DIRECT DISCHARGE
1	2KV	2KV
2	4KV	4KV
3	8KV	6KV
4	15KV	8KV

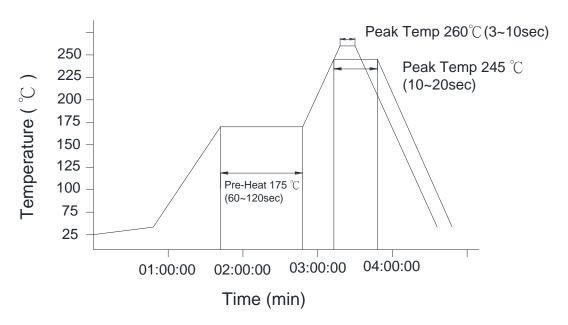
IEC61000-4-2 compliant ESD current pulse waveform

>>Environment Reliability Test

Characteristic	Test Method and Description				
High Temperature Storage	The specimen shall be subjected to 125±2°C for 1000±2 hours without load and then stored at room temperature and normal humidity for one or two hours. The change of varistor voltage shall be within 10%.				
Temperature Cycle	The temperature cycle of specified temperature shall be repeated five times and		Temperature	Period	
			-40±3°C	30±3min	
	then stored at room temperature and normal humidity for one or two hours. The change of varistor voltage shall be within 10% and mechanical damage shall be examined.	2	room temperature	1 hour	
		3	125±3℃	30±3min	
		4	room temperature	1 hour	
High Temperature Load	After being continuously applied the maximum allowable voltage at 85±2°C for 1000±2 hours, the specimen shall be stored at room temperature and normal humidity for one or two hours. The change of varistor voltage shall be within 10%.				
Damp Heat Load/ Humidity Load	The specimen should be subjected to 40±2°C and 90~95% RH, the maximum allowable voltage applied for 1000±2 hours and then stored at room temperature and normal humidity for one or two hours. The change of varistor voltage shall be within 10%.				
Low Temperature Storage	The specimen should be subjected to -40±2℃ for 1000±2 hours without load and then stored at room temperature and normal humidity for one or two hours. The change of varistor voltage shall be within 10%.				



»Soldering Parameters



☆ IR reflow Pb free process suggestion profile

- (1) The solder recommend is Sn96.5/Ag3.5 and thickness recommend as shown in table 5.3
- (2) Ramp-up rate (217°C to peak) +3°C/second max.
- (3) Temp. maintain at 175±25°C 180 seconds max.
- (4) Temp. maintain above 217°C 60~150 seconds